NSN 5962-01-358-9099

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-358-9099

view Offline at https://aerobasegroup.com/nsn/3302-01-330-3033
Body Length:
Between 1.555 inches and 1.595 inches
Body Width:
Between 1.555 inches and 1.595 inches
Body Height:
Between 0.085 inches and 0.115 inches
Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and electrostatic sensitive and w/schmitt trigger and w/resistor
Inclosure Material:
Ceramic
Inclosure Configuration:
Pin grid array
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
28 input
Current Rating Per Characteristic:
10.00 milliamperes forward current, nonrepetitive, peak total value microamperes
Terminal Surface Treatment:
Solder
Product Name:
VIsic gate array (rftag)
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
180 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

Yes - demil/mli

NSN 5962-01-358-9099

Memory Microcircuit - Page 2 of 2



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